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**AN OVERVIEW OF THE MEASUREMENTS OF
THERMOPHYSICAL PROPERTIES AND SOME RESULTS
ON MOLTEN SUPERALLOYS AND SEMICONDUCTORS**

by

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This presentation consists of two parts: (1) comments on the results of measurements on thermophysical properties based on the paper, "Things Mother Never Taught Me (about Thermophysical Properties of Solids)" and (2) results of thermophysical property measurements on selected solid and molten semiconductors and a proprietary superalloy. The first part may be considered as a tutorial for those involved in using or procuring thermophysical property data. The second part is presented as illustrations of what has been accomplished on molten materials at the Thermophysical Properties Research Laboratory (TPRL). The materials include Ge, PbTe, PbSnTe, HgCdTe and a superalloy.

TPRL operates in two modes of operation; graduate level fundamental studies and contract research. As a result of over 30 years of operation, a number of important lessons were learned. These include the fact that all physical properties are inter-related, that thermal conductivity is difficult to determine accurately and that the literature is full of poor results obtained by researchers who had unwarranted faith in their results. Part of

this faith was usually based on the fact that standards were measured and good results were obtained. It was not understood that this is a necessary, but not sufficient condition to obtain reliable results on unknowns, since auxiliary conditions such as softness, emissivity, ability to attach temperature sensors, etc. must also be taken into account.

Thermal diffusivity values for molten semiconductors were obtained using the laser flash technique. Modifications were made in order to contain molten materials. Results were obtained on a number of semiconductors, including Ge, PbSnTe and $\text{Hg}_x\text{Cd}_{1-x}\text{Te}$.

In the case of superalloys, the vapor pressure of constituents such as chromium that have high vapor pressures in the molten region requires that the diffusivity measurements be performed on samples under inert atmosphere (or else sealed samples). The arrangement utilized is indicated in a figure. The sample is contained within a sapphire cup. There is a sapphire lid with spacers that rests on top of the sample. When the sample melts some of it can flow past the spacer. The sample thickness in melt is controlled by the sapphire cup and top. When the sample solidifies, it sometimes generates enough stress to crack the spacer. The purposes of the spacer is as an expendable piece to protect the relatively expensive sapphire top. The laser pulse passes through the sapphire top to heat the top surface of the sample. The resulting rear face temperature rise is obtained by means of an i.r. detector viewing the bottom surface. Since the heat pulse is applied to the top surface, convection is minimized. Thermal diffusivity results are shown in a figure. Measurements in

the solid region were made using the convectional horizontal furnace and the vertical furnace. The diffusivity values exhibit only a change of slope upon melting, even though the apparent specific heat shows a large increase. When one removes the energetics from the apparent specific heat, the calculated thermal conductivity values follow the trend expected from electrical resistivity considerations. The electronic component is calculated using the classical value for the Weidemann-Franz-Lorenz ratio and as such is known to be about 10% smaller than the total thermal conductivity since thermal and electrical conductivities were measured on the solid sample up to 600°C using the Kohlrausch technique. These total thermal conductivity values lie on the same curve as those calculated from diffusivity/specific heat determinations. Note that specific heat determinations made elsewhere by levitation calorimeter are in error by more than 300%.

THERMOPHYSICAL PROPERTIES RESEARCH LABORATORY
SCHOOL OF MECHANICAL ENGINEERING
PURDUE UNIVERSITY

ACTIVITIES

- (1) FUNDAMENTAL STUDIES**
 - A. MATERIAL PROPERTIES**
 - B. TECHNIQUE DEVELOPMENT**
- (2) CONTRACT RESEARCH**

GOALS

- (1) EDUCATE STUDENTS AND PROFESSIONALS**
- (2) CRITICALLY EVALUATE TECHNIQUES**
- (3) FURTHER UNDERSTANDING OF
MECHANISMS OF ENERGY TRANSPORT**
- (4) PROVIDE USEFUL SERVICE FOR
OUTSIDE ORGANIZATIONS**
- (5) RESOLVE SERIOUS DISCORDS IN
EXISTING INFORMATION**

Lesson 1 :

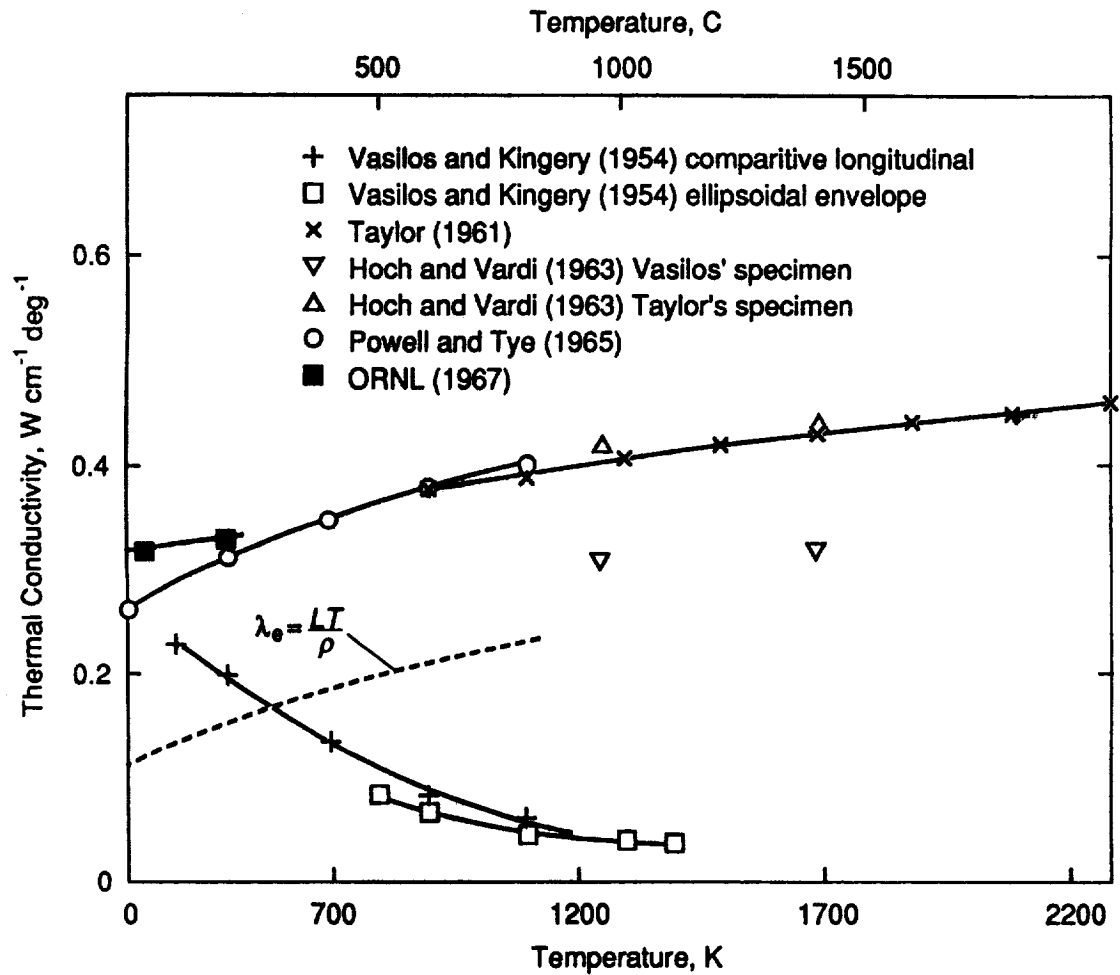
**Properties are
Inter- and Intra- Related and are
Non-Denominational**

- (1) $\lambda_e = L_0 T / \rho$ (Thermal-electrical)
- (2) $\lambda_p = 1/3 C_v v \ell$ (Thermal-mechanical)
- (3) $\epsilon(0, T) = 0.578 (\rho T)^{1/2} - 0.178 \rho T + 0.0514 (\rho T)^{3/2}$ (Radiative-electrical)
- (4) $Y = 2G(1 + \nu)$ Mechanical-chemical bonding
 - $\nu = 0.25$ Ionic or Van der Waal bonding
 - $\nu < 0.25$ Covalent bonding
 - $\nu > 0.25$ Metallic or elastic bonding
- (5) $C_p - C_v = B_v^2 T V / \chi$ (Thermal-mechanical)

Lesson 3 :

Thermal conductivity is difficult to measure accurately

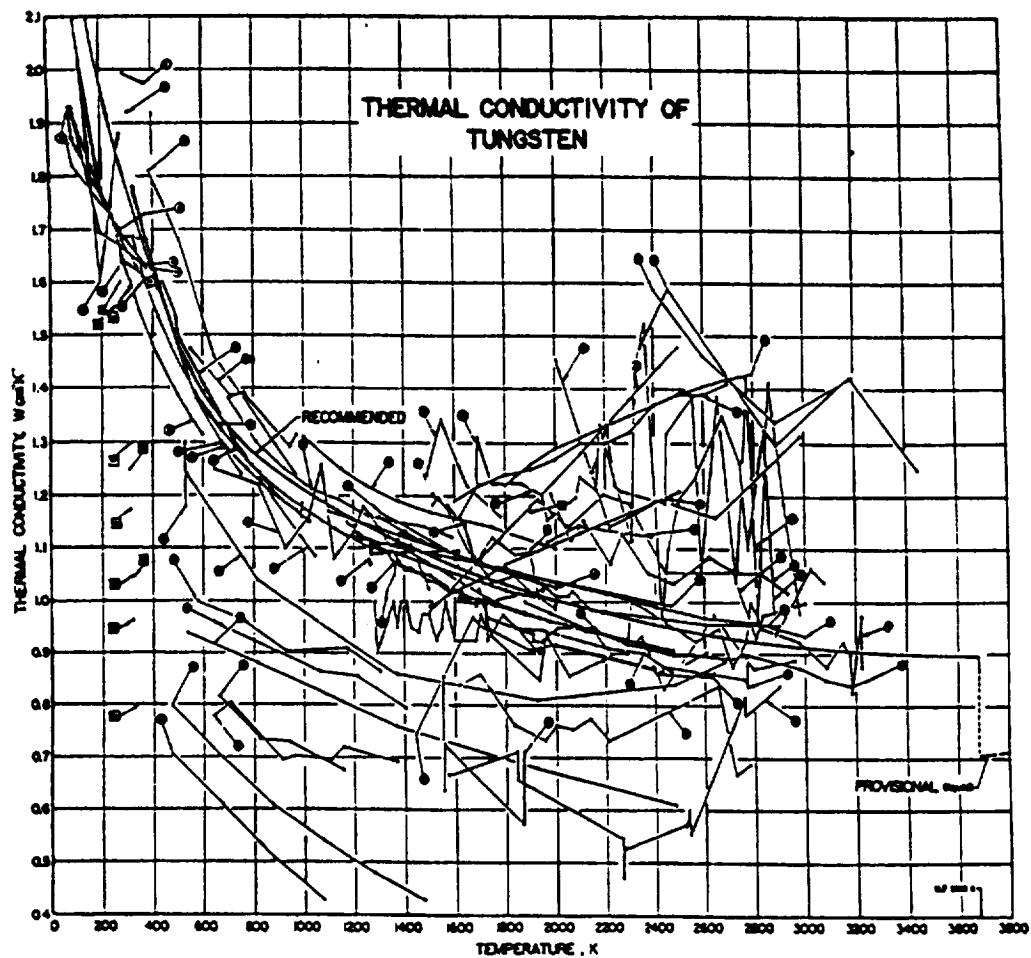
"DIRECT" measurement involves determining $T, \Delta T, Q$



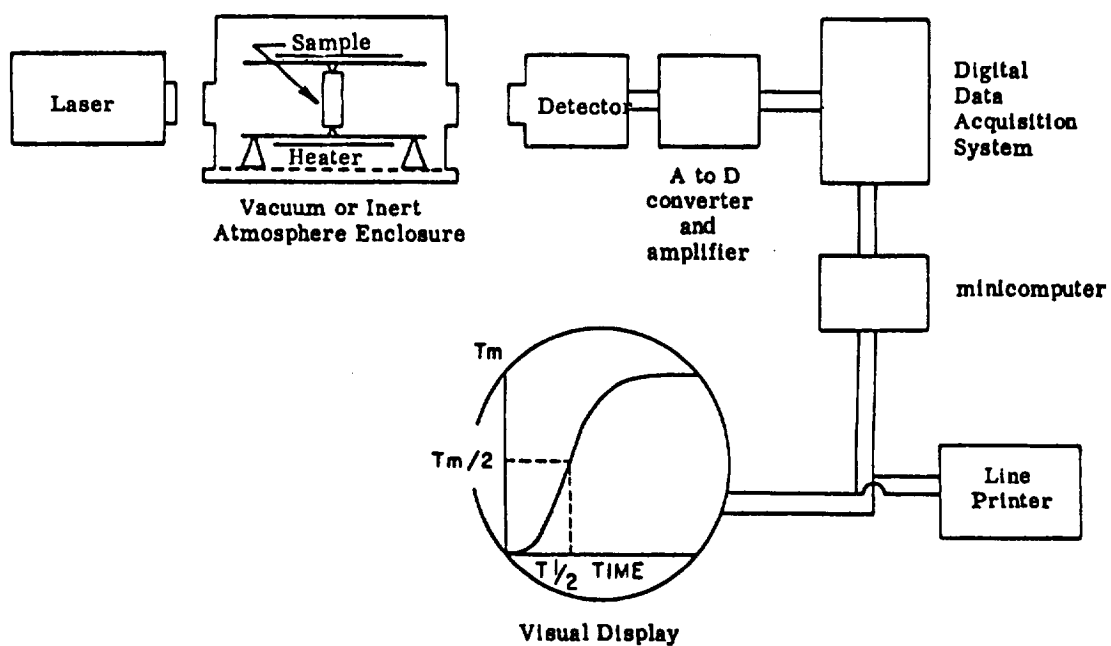
Lesson 4 :

Reference materials and standards for

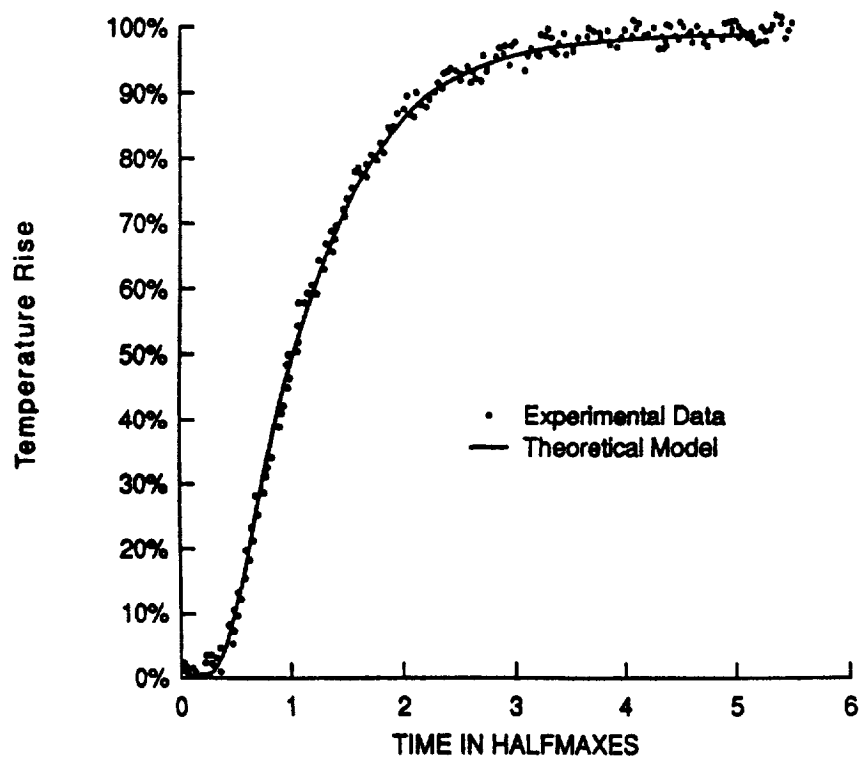
methods **ARE VERY DANGEROUS**



Thermal Conductivity of Tungsten



Flash Diffusivity (Schematic)



On-Line Comparison of Experimental Rise curve
to Theoretical Model

TABLE 2

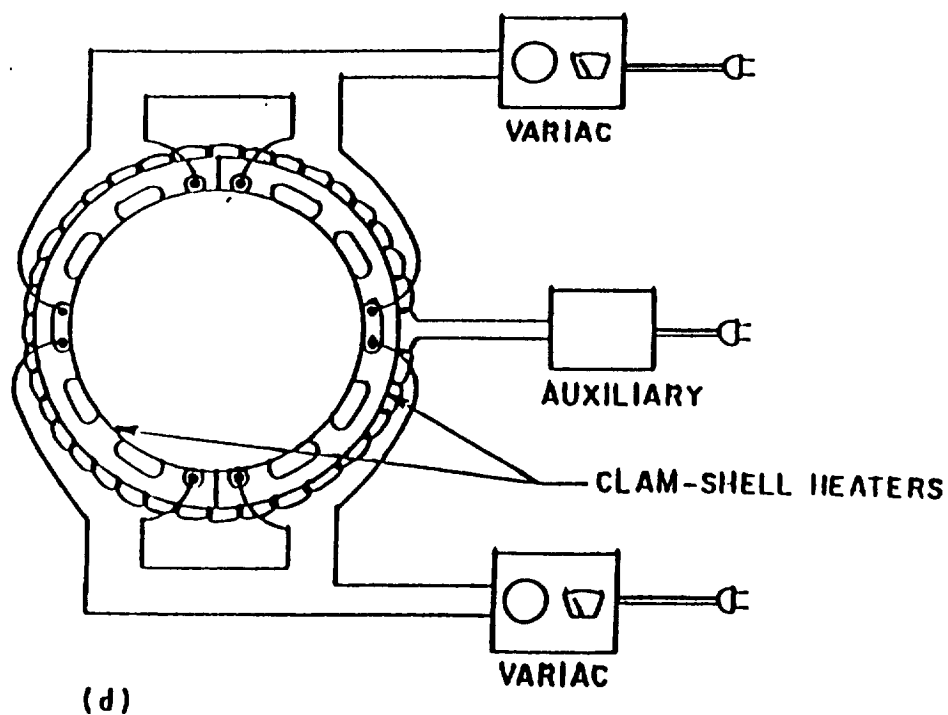
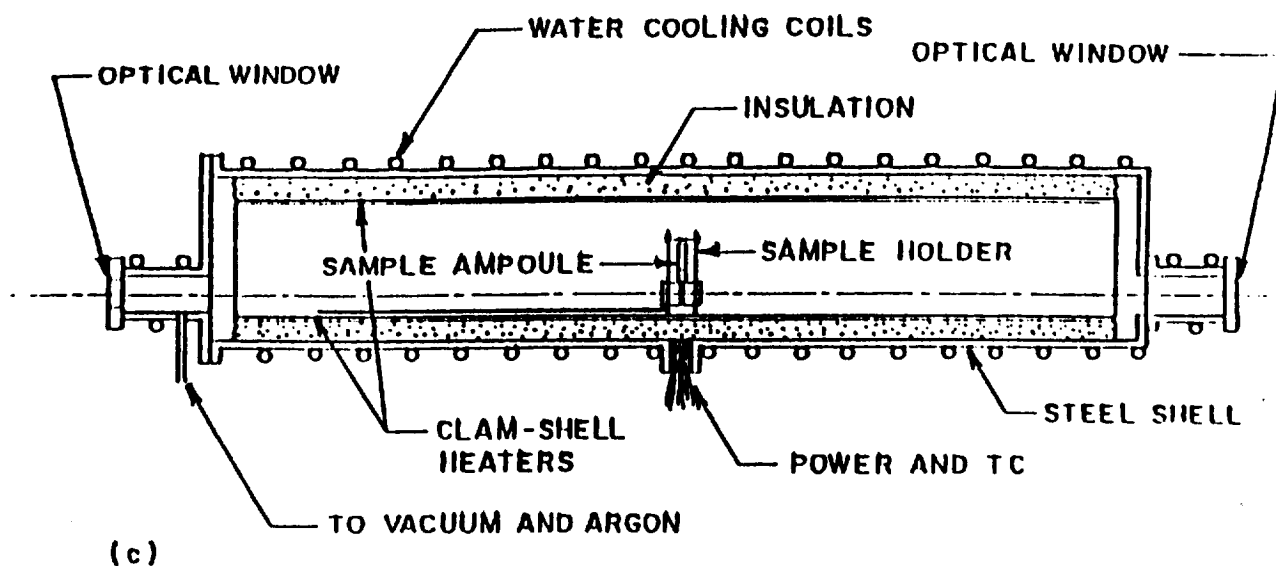
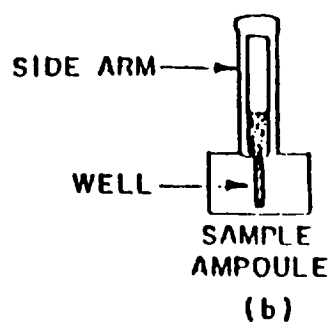
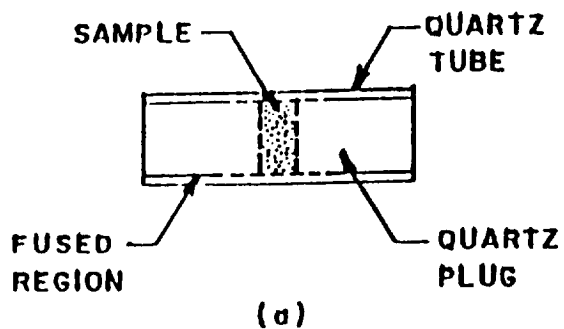
COMPUTER OUTPUT FOR DIFFUSIVITY EXPERIMENT
(F142GG2 at 313 K)

Sample: F142GG2

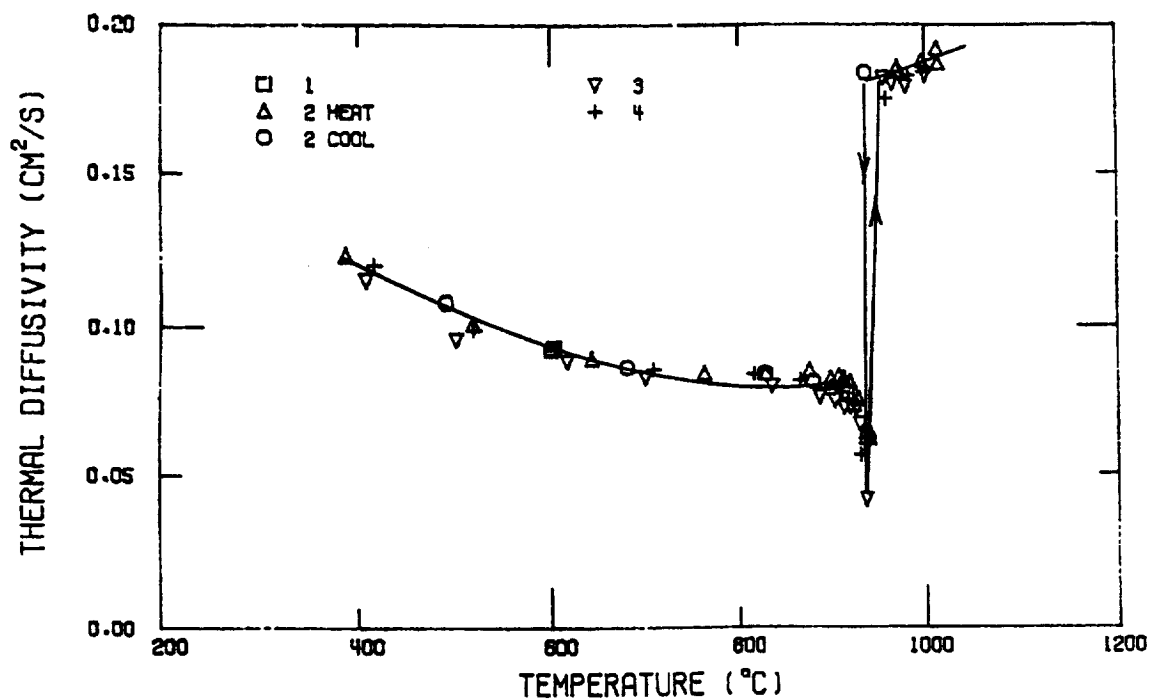
Temp: 1.627 MV = 313 K

Max: 5.40477 Volts Halfmax.: 3.58397 Volts Baseline: 1.870 Volts

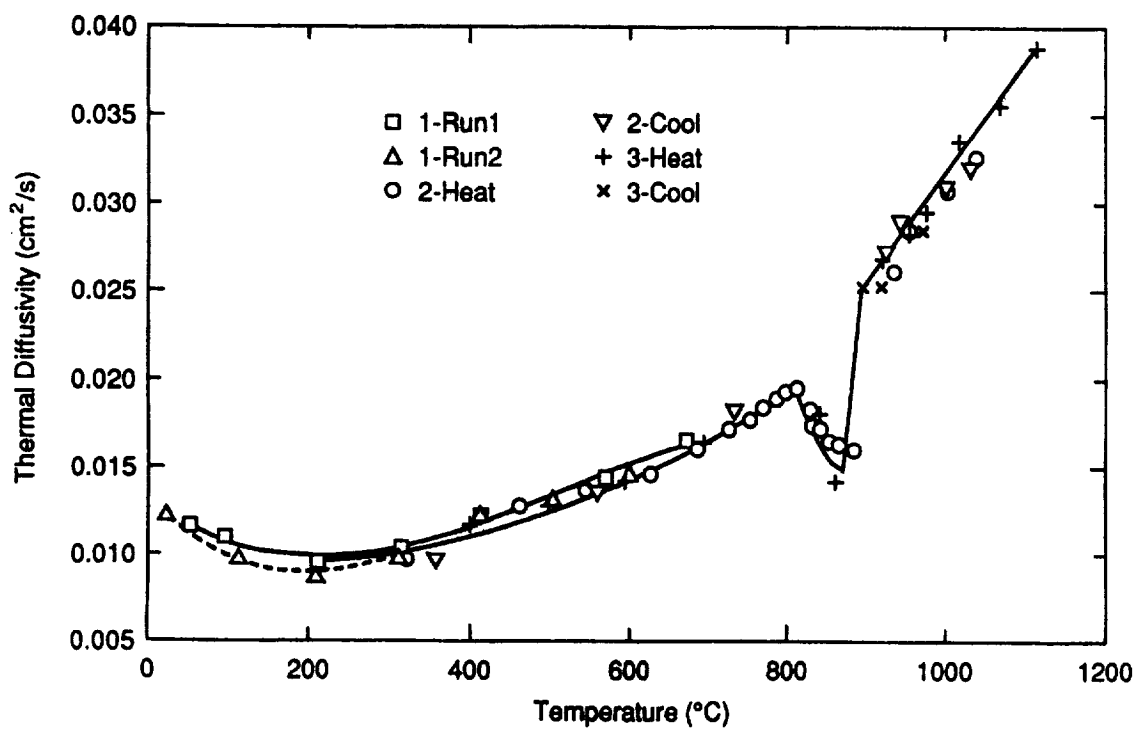
ALPHA (cm ² /sec)	PER (%)	VALUE (Volts)	TIME (Seconds)
0.8292	20	2.57695	0.023793
0.8315	25	2.75369	0.026113
0.8313	30	2.93043	0.028589
0.8374	33.3	3.04826	0.029275
0.8291	40	3.28391	0.033008
0.8347	50	3.63739	0.038935
0.8416	60	3.99086	0.041497
0.8466	66.7	4.22652	0.049997
0.8304	70	4.34434	0.054108
0.8451	75	4.52108	0.058326
0.8389	80	4.69782	0.065112



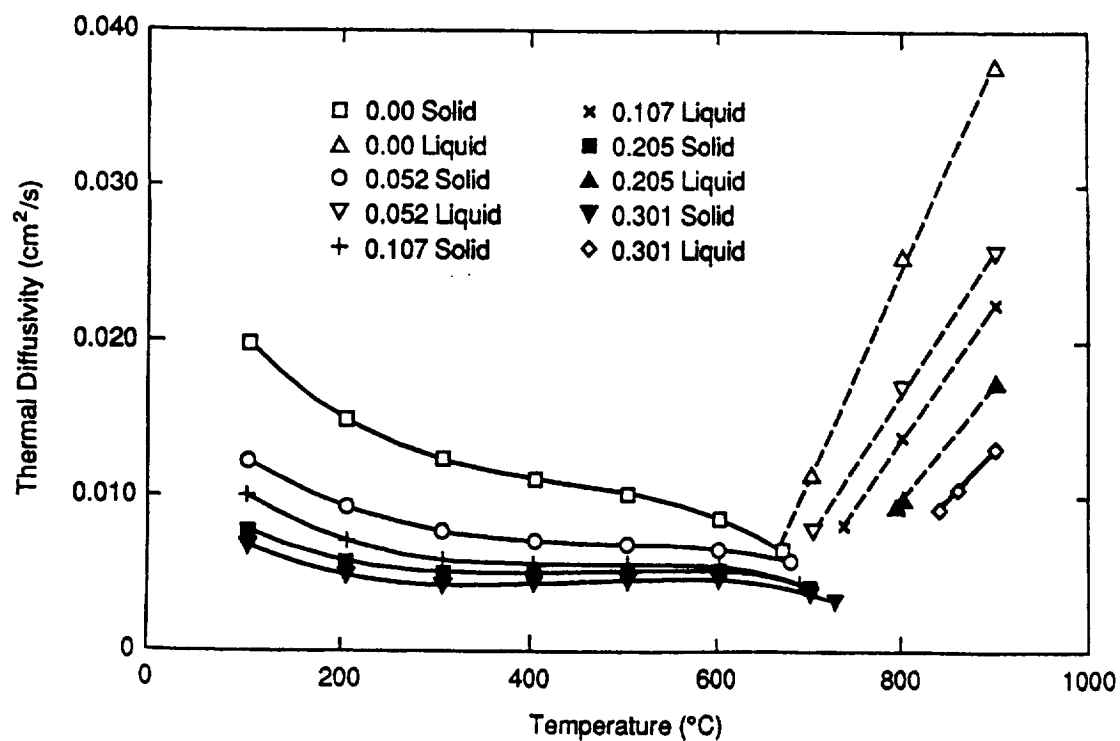
Schematic of Laser Flash for Molten Semiconductors



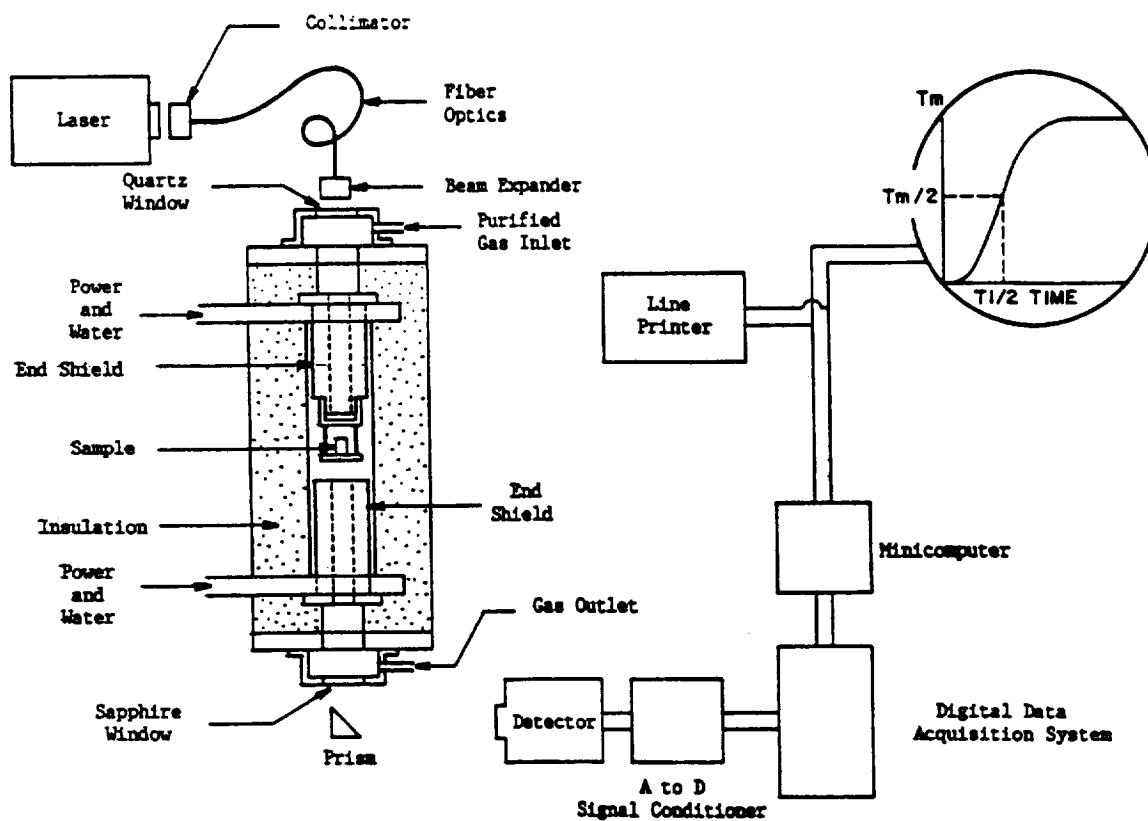
Thermal Diffusivity of Four Ge Samples Showing Effects of Melting, Super-Cooling and Cooling



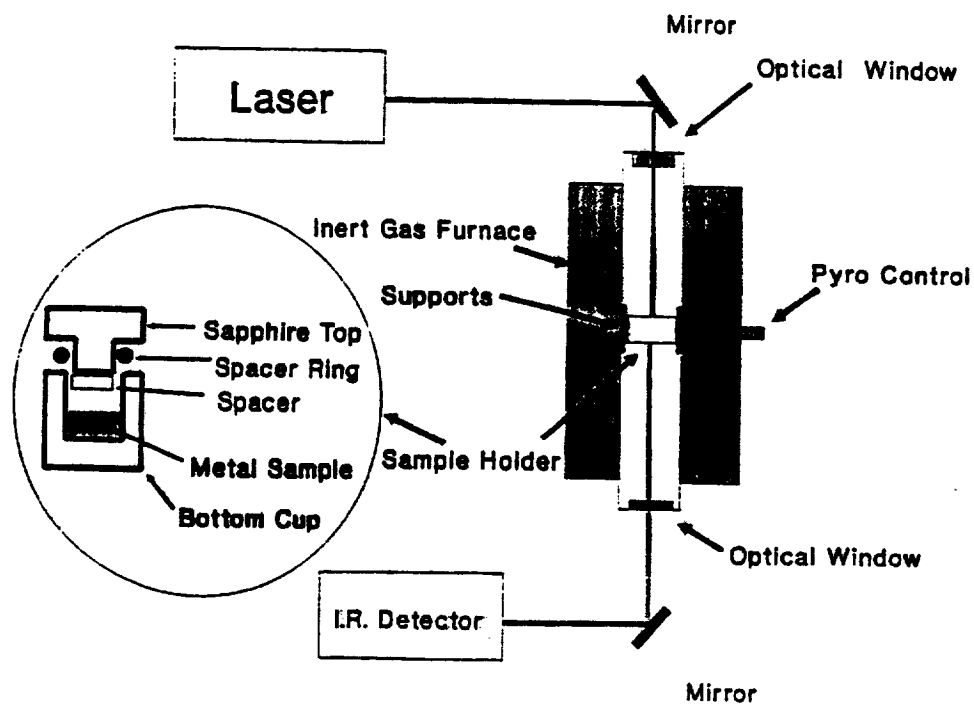
Thermal Diffusivity of Three Samples of Pb Sn Te



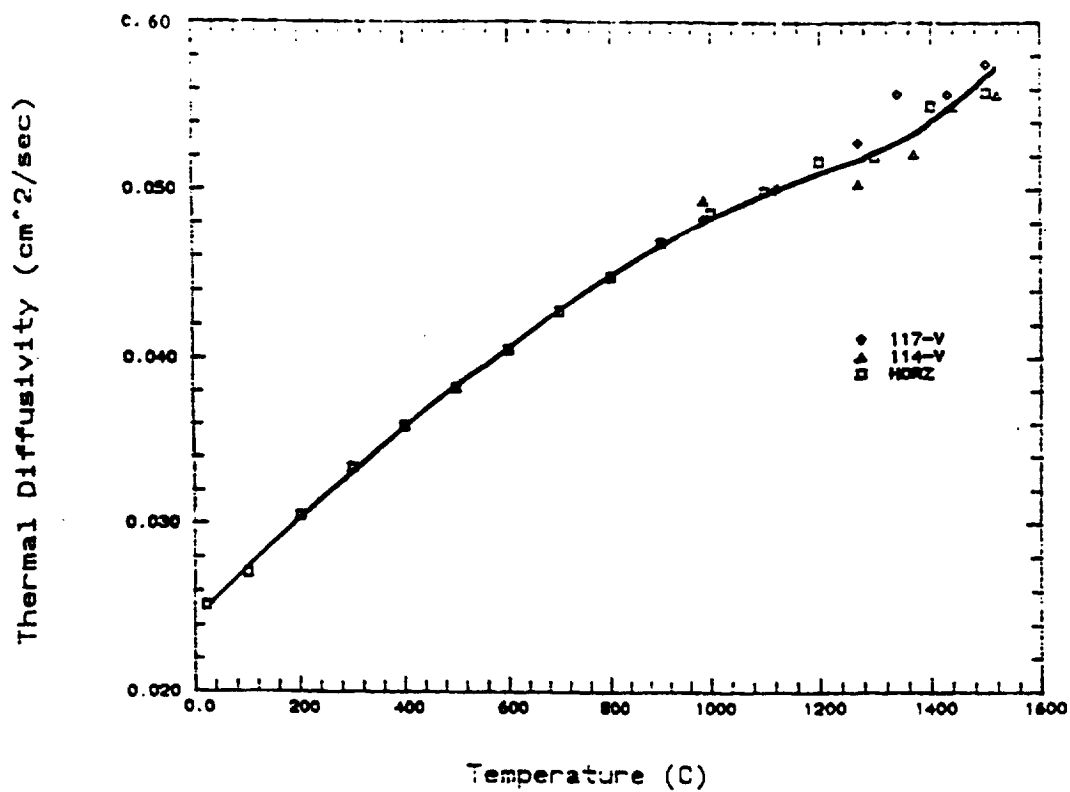
Thermal Diffusivity of $\text{Hg}_x\text{Cd}_{1-x}\text{Te}$ ($0 \leq x \leq 0.301$)



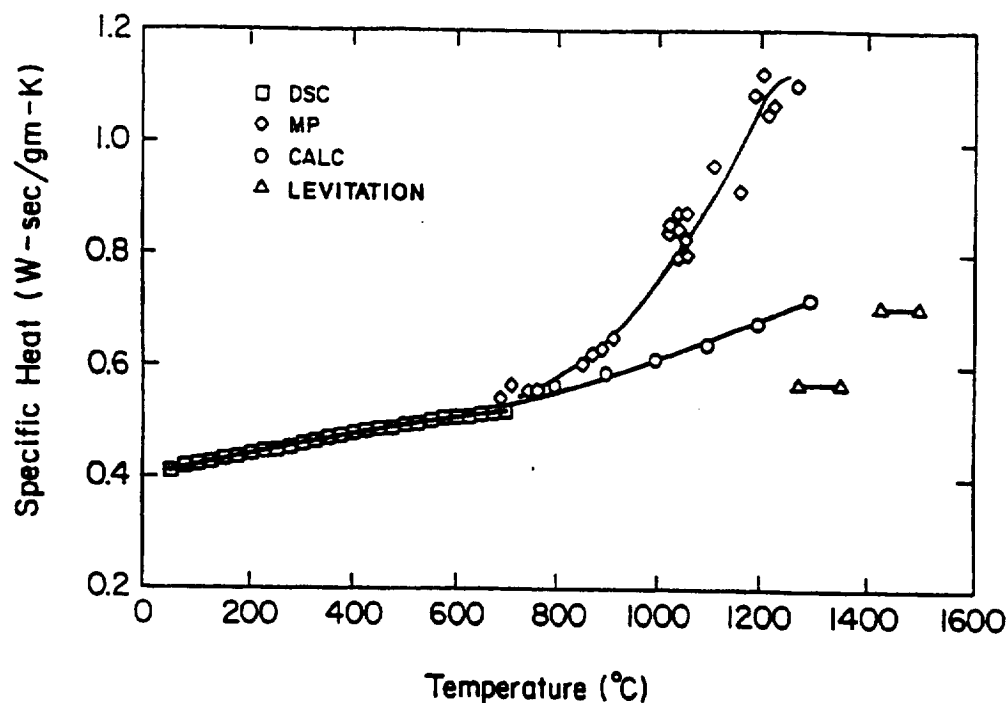
Schematic of Laser Flash Diffusivity Apparatus for Molten Superalloys



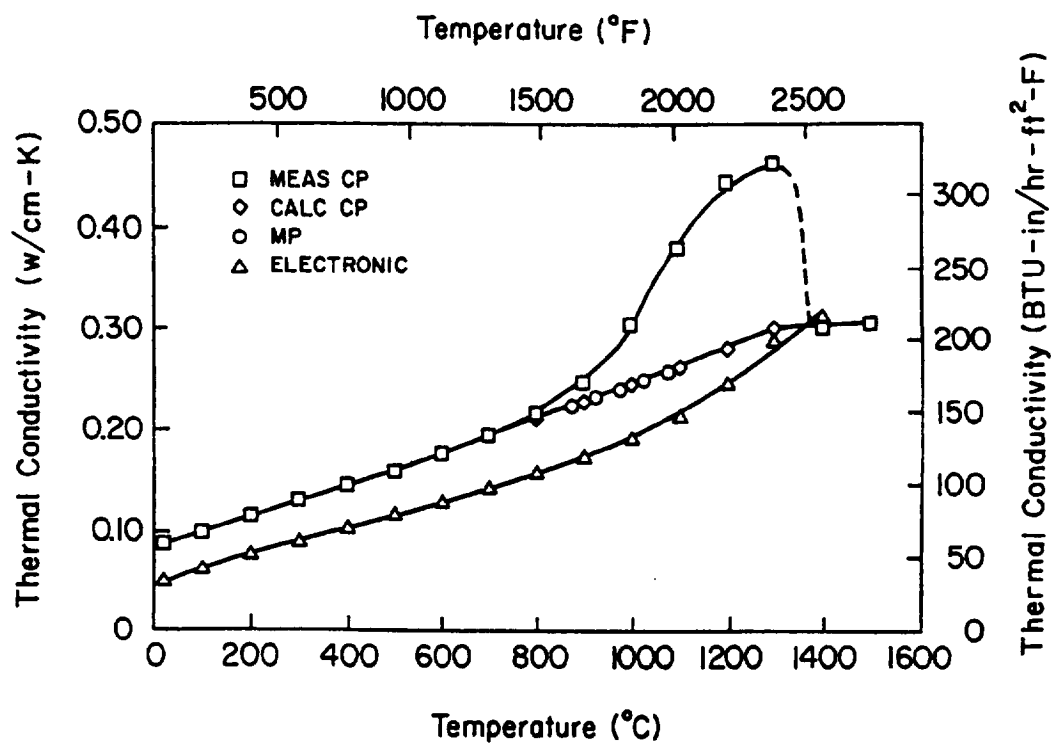
Details of Sample Holder for Molten Alloys



Thermal Diffusivity of Two Samples of a Proprietary Superalloy using both Horizontal and Vertical Furnaces



Specific Heat of a proprietary Superalloy
(Note values Obtained by Levitation are in error by 300%)



Thermal Conductivity of a Proprietary Superalloy
(Values Indicated by Curves Designated by MEAS CP are valid to 800°C and Those Designated by MP and CALC CP are valid above 800°C)

